

# HD74LV27A

# Triple 3-input Positive NOR Gates

REJ03D0238-0300Z (Previous ADE-205-256A (Z)) Rev.3.00 Jun. 01, 2004

### **Description**

The HD74LV27A performs the Boolean functions  $Y = \overline{A} \cdot \overline{B} \cdot \overline{C}$  or  $Y = \overline{A + B + C}$  in positive logic.

Low-voltage and high-speed operation is suitable for the battery-powered products (e.g., notebook computers), and the low-power consumption extends the battery life.

#### **Features**

- $V_{CC} = 2.0 \text{ V to } 5.5 \text{ V operation}$
- All inputs  $V_{IH}$  (Max.) = 5.5 V (@ $V_{CC}$  = 0 V to 5.5 V)
- All outputs  $V_0$  (Max.) = 5.5 V (@ $V_{CC}$  = 0 V)
- Typical  $V_{OL}$  ground bounce < 0.8 V (@ $V_{CC}$  = 3.3 V, Ta = 25°C)
- Typical  $V_{OH}$  undershoot > 2.3 V (@ $V_{CC}$  = 3.3 V, Ta = 25°C)
- Output current  $\pm 6$  mA (@V<sub>CC</sub> = 3.0 V to 3.6 V),  $\pm 12$  mA (@V<sub>CC</sub> = 4.5 V to 5.5 V)
- Ordering Information

Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)
HD74LV27AFPEL	SOP-14 pin(JEITA)	FP-14DAV	FP	EL (2,000 pcs/reel)
HD74LV27ARPEL	SOP-14 pin(JEDEC)	FP-14DNV	RP	EL (2,500 pcs/reel)
HD74LV27ATELL	TSSOP-14 pin	TTP-14DV	Т	ELL (2,000 pcs/reel)

Note: Please consult the sales office for the above package availability.

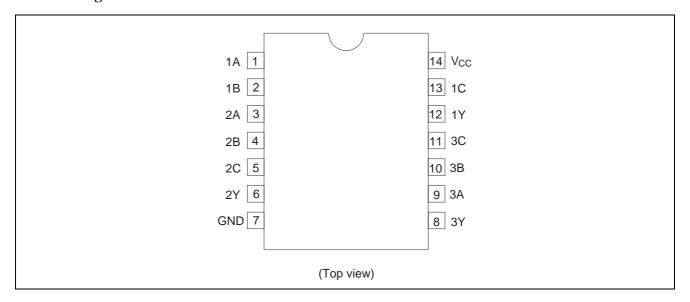
#### **Function Table**

#### Inputs

Α	В	С	Output Y
Н	X	X	L
X	Н	X	L
X	X	Н	L
L	L	L	Н

Note: H: High level L: Low level X: Immaterial

### **Pin Arrangement**



## **Absolute Maximum Ratings**

Item	Symbol	Ratings	Unit	Conditions
Supply voltage range	V <sub>CC</sub>	-0.5 to 7.0	V	
Input voltage range*1	Vı	-0.5 to 7.0	V	
Output voltage range*1,2	Vo	-0.5 to V <sub>CC</sub> + 0.5	V	Output: H or L
		-0.5 to 7.0		V <sub>CC</sub> : OFF
Input clamp current	l <sub>IK</sub>	-20	mA	V <sub>I</sub> < 0
Output clamp current	lok	±50	mA	$V_O < 0$ or $V_O > V_{CC}$
Continuous output current	I <sub>O</sub>	±25	mA	$V_O = 0$ to $V_{CC}$
Continuous current through V <sub>CC</sub> or GND	I <sub>CC</sub> or I <sub>GND</sub>	±50	mA	
Maximum power dissipation at	P <sub>T</sub>	785	mW	SOP
Ta = 25°C (in still air)*3		500		TSSOP
Storage temperature	Tstg	-65 to 150	°C	

Notes: The absolute maximum ratings are values, which must not be individually be exceeded, and furthermore, no two of which may be realized at the same time.

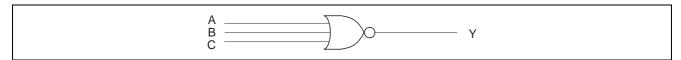
- 1. The input and output voltage ratings may be exceeded even if the input and output clamp-current ratings are observed.
- 2. This value is limited to 5.5 V maximum.
- 3. The maximum package power dissipation was calculated using a junction temperature of 150°C.

## **Recommended Operating Conditions**

Item	Symbol	Min	Max	Unit	Conditions
Supply voltage range	Vcc	2.0	5.5	V	
Input voltage range	Vı	0	5.5	V	
Output voltage range	Vo	0	V <sub>CC</sub>	V	
Output current	I <sub>OH</sub>	_	-50	μΑ	V <sub>CC</sub> = 2.0 V
		_	-2	mA	V <sub>CC</sub> = 2.3 to 2.7 V
		_	-6		V <sub>CC</sub> = 3.0 to 3.6 V
		_	-12		V <sub>CC</sub> = 4.5 to 5.5 V
	I <sub>OL</sub>	_	50	μΑ	V <sub>CC</sub> = 2.0 V
		_	2	mA	$V_{CC} = 2.3 \text{ to } 2.7 \text{ V}$
		_	6		$V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$
		_	12		V <sub>CC</sub> = 4.5 to 5.5 V
Input transition rise or fall rate	Δt /Δν	0	200	ns/V	V <sub>CC</sub> = 2.3 to 2.7 V
		0	100		V <sub>CC</sub> = 3.0 to 3.6 V
		0	20		V <sub>CC</sub> = 4.5 to 5.5 V
Operating free-air temperature	Та	-40	85	°C	

Note: Unused or floating inputs must be held high or low.

## Logic Diagram



## **DC Electrical Characteristics**

Ta = -40 to  $85^{\circ}C$ 

Item	Symbol	V <sub>CC</sub> (V)*	Min	Тур	Max	Unit	Test Conditions
Input voltage	V <sub>IH</sub>	2.0	1.5	_	_	V	
		2.3 to 2.7	$V_{CC} \times 0.7$	_	_		
		3.0 to 3.6	$V_{CC} \times 0.7$	_	_		
		4.5 to 5.5	$V_{CC} \times 0.7$	_	_		
	V <sub>IL</sub>	2.0	_	_	0.5		
		2.3 to 2.7	_	_	$V_{CC} \times 0.3$		
		3.0 to 3.6	_	_	$V_{\text{CC}}\!\times\!0.3$		
		4.5 to 5.5	_	_	$V_{CC} \times 0.3$		
Output voltage	V <sub>OH</sub>	Min to Max	V <sub>CC</sub> - 0.1	_	_	V	$I_{OH} = -50 \mu A$
		2.3	2.0	_	_		$I_{OH} = -2 \text{ mA}$
		3.0	2.48	_	_		$I_{OH} = -6 \text{ mA}$
		4.5	3.8	_	_		$I_{OH} = -12 \text{ mA}$
	V <sub>OL</sub>	Min to Max	_	_	0.1		$I_{OL} = 50 \mu A$
		2.3	_	_	0.4		I <sub>OL</sub> = 2 mA
		3.0	_	_	0.44		I <sub>OL</sub> = 6 mA
		4.5	_	_	0.55		I <sub>OL</sub> = 12 mA
Input current	I <sub>IN</sub>	0 to 5.5	_	_	±1	μΑ	$V_{IN} = 5.5 \text{ V or GND}$
Quiescent supply	Icc	5.5	_	_	20	μΑ	$V_{IN} = V_{CC}$ or GND, $I_O = 0$
current							
Output leakage current	I <sub>OFF</sub>	0	_	_	5	μΑ	$V_1$ or $V_0 = 0$ V to 5.5 V
Input capacitance	C <sub>IN</sub>	3.3	_	3.5	_	pF	$V_I = V_{CC}$ or GND

Note: For conditions shown as Min or Max, use the appropriate values under recommended operating conditions.

## **Switching Characteristics**

 $V_{CC}=2.5\pm0.2\ V$ 

		Ta =	25°C		Ta = -40 to 85°C		Test	FROM	ТО	
Item	Symbol	Min	Тур	Max	Min	Max	Unit	Conditions	(Input)	(Output)
Propagation	t <sub>PLH</sub>	_	8.3	13.8	1.0	16.0	ns	C <sub>L</sub> = 15 pF	А, В,	Υ
delay time	$t_{PHL}$	_	10.0	17.5	1.0	21.0		C <sub>L</sub> = 50 pF	or C	

 $V_{CC} \equiv 3.3 \pm 0.3~V$ 

		Ta =	25°C		Ta = -4	Ta = -40 to 85°C		Test	FROM	то
Item	Symbol	Min	Тур	Max	Min	Max	Unit	Conditions	(Input)	(Output)
Propagation	t <sub>PLH</sub>	_	6.2	8.8	1.0	10.5	ns	C <sub>L</sub> = 15 pF	А, В,	Υ
delay time	$t_{PHL}$	_	8.7	12.3	1.0	14.0		C <sub>L</sub> = 50 pF	or C	

 $V_{CC}=5.0\pm0.5\ V$ 

		Ta = :	25°C		Ta = -4	10 to 85°C	_	Test	FROM	то
Item	Symbol	Min	Тур	Max	Min	Max	Unit	Conditions	(Input)	(Output)
Propagation	t <sub>PLH</sub>	_	4.1	5.9	1.0	7.0	ns	C <sub>L</sub> = 15 pF	A, B,	Υ
delay time	$t_{PHL}$	_	5.6	7.9	1.0	9.0		C <sub>L</sub> = 50 pF	or C	

## **Operating Characteristics**

 $C_L = 50 \text{ pF}$ 

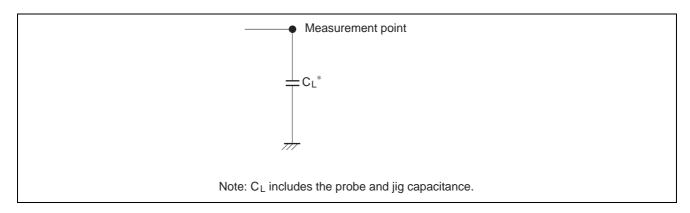
			Ta = 25	5°C			
Item	Symbol	V <sub>CC</sub> (V)	Min	Тур	Max	Unit	Test Conditions
Power dissipation capacitance	$C_{PD}$	3.3	_	9.5	_	pF	f = 10 MHz
		5.0	_	11.0	_		

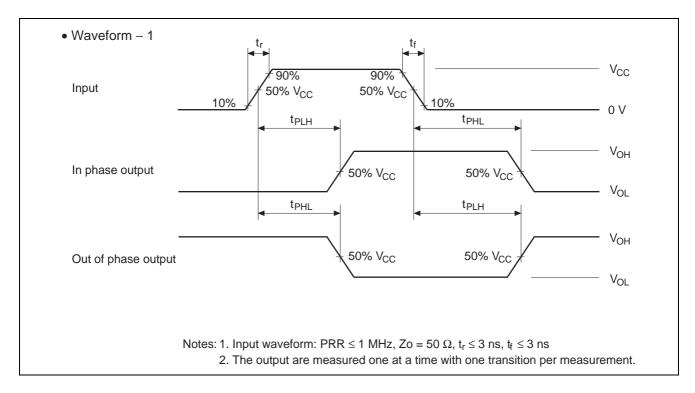
## **Noise Characteristics**

 $C_L = 50 \text{ pF}$ 

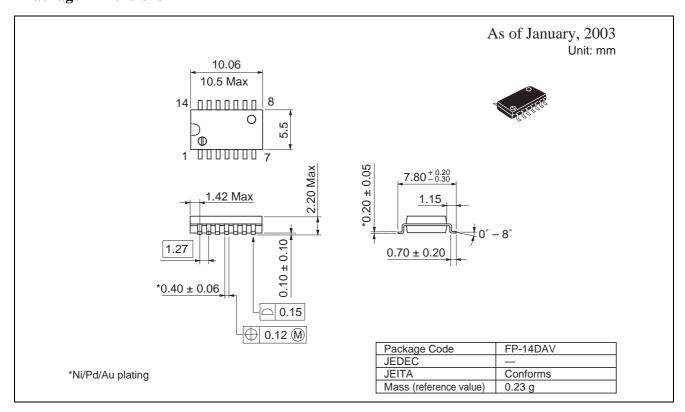
			Ta = 25	5°C			L I
Item	Symbol	V <sub>CC</sub> (V)	Min	Тур	Max	Unit	Test Conditions
Quiet output, maximum dynamic V <sub>OL</sub>	V <sub>OL (P)</sub>	3.3	_	0.2	0.8	V	
Quiet output, minimum dynamic V <sub>OL</sub>	V <sub>OL (V)</sub>	3.3	_	-0.1	-0.8	V	
Quiet output, minimum dynamic V <sub>OH</sub>	$V_{OH\ (V)}$	3.3	_	3.2	_	V	
High-level dynamic input voltage	$V_{\text{IH }(D)}$	3.3	2.31	_	_	V	
Low-level dynamic inout voltage	V <sub>IL (D)</sub>	3.3	_	_	0.99	V	

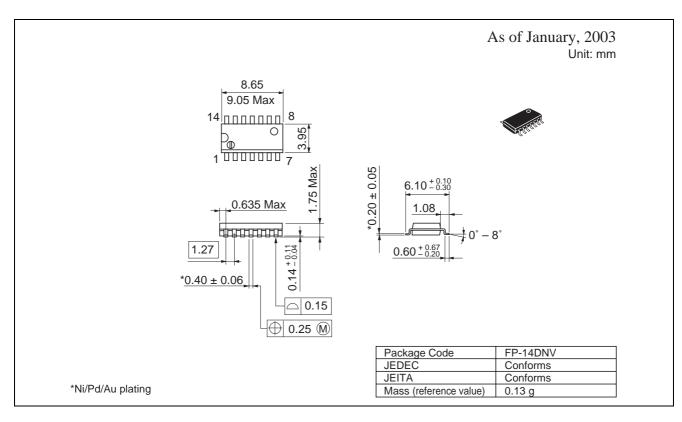
### **Test Circuit**

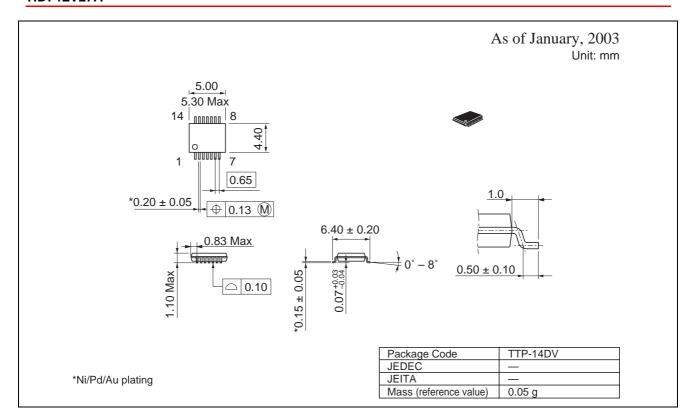




## **Package Dimensions**







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